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# P-Channel 12 V (D-S) MOSFET

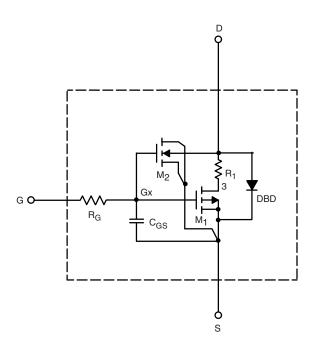
#### **DESCRIPTION**

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### SUBCIRCUIT MODEL SCHEMATIC

#### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- · Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# **SPICE Device Model Si7405BDN**

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SPECIFICATIONS (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	0.65	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_D = -13.5 \text{ A}$	0.009	0.009	Ω
		$V_{GS} = -2.5 \text{ V}, I_D = -12 \text{ A}$	0.012	0.012	
		$V_{GS} = -1.8 \text{ V}, I_D = -4.2 \text{ A}$	0.016	0.016	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 6 V, I <sub>D</sub> = - 13.5 A	53	55	S
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = - 10 A	- 0.84	- 0.80	V
Dynamic <sup>b</sup>	•				
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -6 V, V <sub>GS</sub> = 0 V, f = 1 MHz	3460	3500	pF
Output Capacitance	C <sub>oss</sub>		1093	910	
Reverse Transfer Capacitance	C <sub>rss</sub>		962	860	
Total Gate Charge	Qg	V <sub>DS</sub> = -6 V, V <sub>GS</sub> = -8 V, I <sub>D</sub> = -10 A	59	75	nC
		V <sub>DS</sub> = -6 V, V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -10 A	37	46	
Gate-Source Charge	Q <sub>gs</sub>		4.5	4.5	
Gate-Drain Charge	Q <sub>gd</sub>		14	14	

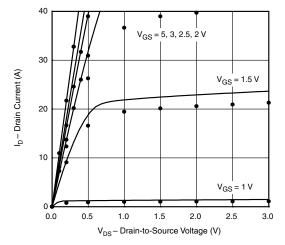
#### Notes

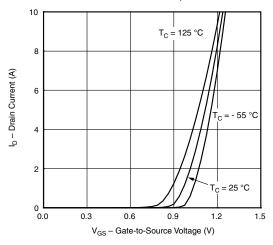
- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

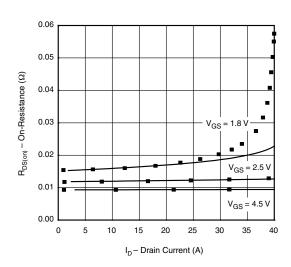
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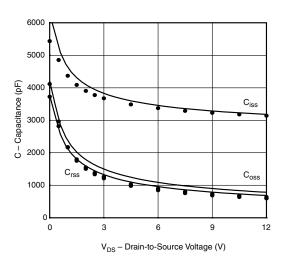
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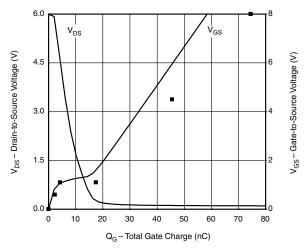
### **COMPARISON OF MODEL WITH MEASURED DATA** ( $T_J = 25$ °C, unless otherwise noted)

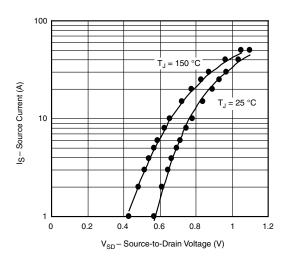












#### Note

• Dots and squares represent measured data.



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